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HMC460LC5* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

HMC460LC5 Evaluation Board

Documentation 🖵

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

• HMC460LC5: GaAs pHEMT MMIC Low Noise Amplifier, DC - 20 GHz Data Sheet

Tools and Simulations

• HMC460LC5 S-Parameters

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: LC5, LC5A (QTR: 2014-00384 REV: 01)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

Design Resources 🖵

- HMC460LC5 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

Discussions 🖵

View all HMC460LC5 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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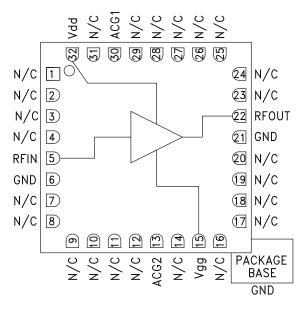


Typical Applications

The HMC460LC5 is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation

Functional Diagram



HMC460LC5

GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

Features

Noise Figure: 2.5 dB @ 10 GHz Gain: 14 dB @ 10 GHz P1dB Output Power: +16.5 dBm @ 10 GHz Supply Voltage: +8V @ 75 mA 50 Ohm Matched Input/Output 32 Lead Ceramic 5x5mm SMT Package: 25mm²

General Description

The HMC460LC5 is a GaAs MMIC pHEMT Low Noise Distributed Amplifier in a leadless 5x5 mm ceramic surface mount package which operates from DC to 20 GHz. The amplifier provides 14 dB of gain, 2.5 dB noise figure and +16.5 dBm of output power at 1 dB gain compression while requiring only 75 mA from a Vdd = 8V supply. Gain flatness is excellent from DC to 20 GHz making the HMC460LC5 ideal for EW, ECM, Radar and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd= 8V, Idd= 75 mA*

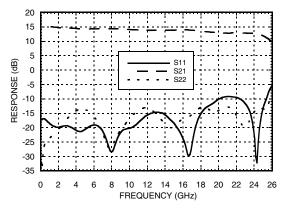
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	DC - 6.0		6.0 - 18.0		18.0 - 20.0			GHz		
Gain	11	14		11	14		10	13		dB
Gain Flatness		± 0.5			± 0.15			± 0.25		dB
Gain Variation Over Temperature		0.008			0.01			0.01		dB/ °C
Noise Figure		3.5	5.0		2.5	4.0		3.5	5	dB
Input Return Loss		17			18			12		dB
Output Return Loss		17			15			15		dB
Output Power for 1 dB Compression (P1dB)	14	17		13	16		12	15		dBm
Saturated Output Power (Psat)		18			18			17		dBm
Output Third Order Intercept (IP3)		29.5			29			28.5		dBm
Supply Current (Idd) (Vdd= 8V, Vgg= -0.9V Typ.)		75			75			75		mA

* Adjust Vgg between -2 to 0V to achieve Idd= 75 mA typical.

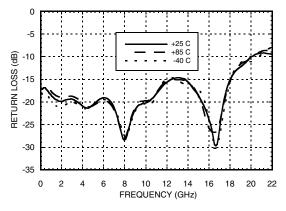


ROHSV EARTH FRIEND

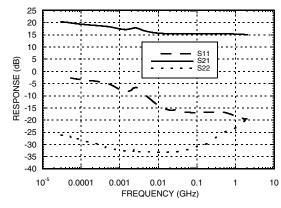
Broadband Gain & Return Loss



Input Return Loss vs. Temperature



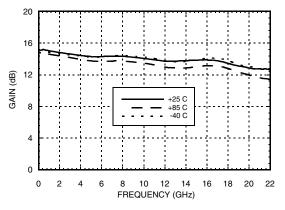
Low Frequency Gain & Return Loss



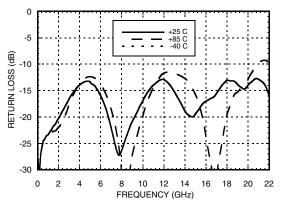
GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

HMC460LC5

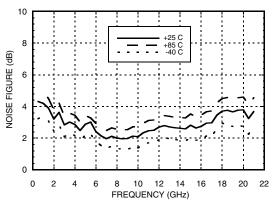
Gain vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature

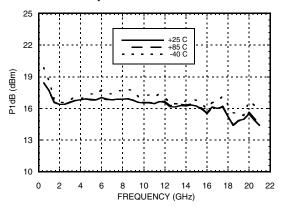




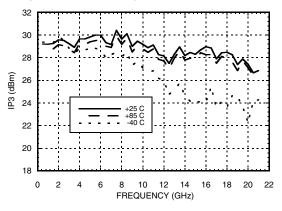


ROHS EARTH FRIENDL

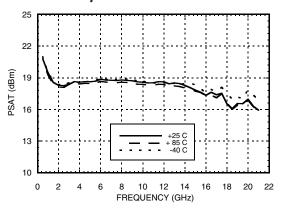
P1dB vs. Temperature



Output IP3 vs. Temperature



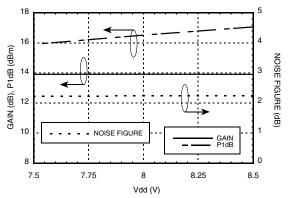
Psat vs. Temperature

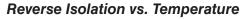


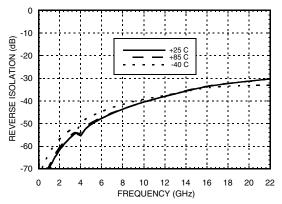
GaAs pHEMT MMIC LOW NOISE

AMPLIFIER, DC - 20 GHz

Gain, Power & Noise Figure vs. Supply Voltage @ 10 GHz, Fixed Vgg











GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+9 Vdc
Gate Bias Voltage (Vgg)	-2 to 0 Vdc
Gate Bias Voltage (Igg)	2.5 mA
RF Input Power (RFIN)(Vdd = +8 Vdc)	+18 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85 °C) (derate 23 mW/°C above 85 °C)	2 W
Thermal Resistance (channel to package bottom)	44.4 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C

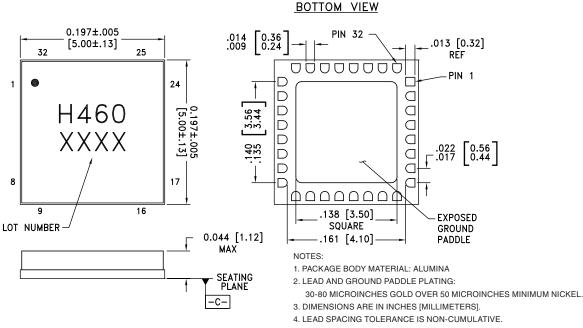
Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
+7.5	74
+8.0	75
+8.5	76



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



5 PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]	
HMC460LC5	Alumina, White	Gold over Nickel	MSL3 ^[1]	H460 XXXX	

[1] Max peak reflow temperature of 260 $^\circ\text{C}$

[2] 4-Digit lot number XXXX





GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

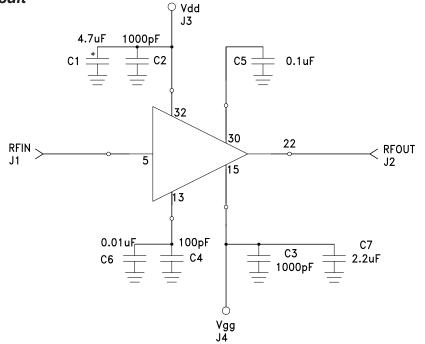
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 4, 7 - 12, 14, 16 - 20, 23 - 29, 31	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
5	RFIN	This pin is DC coupled and matched to 50 Ohms.	RFIN ACG2
6, 21	GND	Package bottom must be connected to RF/DC ground.	
13	ACG2	Low frequency termination. Attach bypass capacitor per application circuit herein.	RFIN ACG2
15	Vgg	Gate control for amplifier. Please follow"MMIC Amplifier Biasing Procedure" application note	VggO
22	RFOUT	This pin is DC coupled and matched to 50 Ohms.	O RFOUT
30	ACG1	Low frequency termination. Attach bypass capacitor per application circuit herein.	
32	Vdd	Power supply voltage for the amplifier. External bypass capacitors are required	 ↓ ↓ ↓ ↓ ↓



GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

Application Circuit



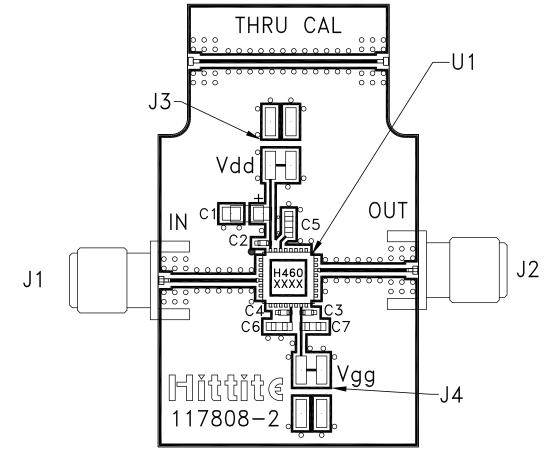




GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz



Evaluation PCB



List of Materials for Evaluation PCB 117810 [1]

Γ	
Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	2 mm Molex Header
C4	100 pF Capacitor, 0402 Pkg.
C2, C3	1000 pF Capacitor, 0402 Pkg.
C1	4.7 µF Capacitor, Tantalum
C5	0.1 uF Capacitor, 0603 Pkg.
C6	0.01 uF Capacitor, 0603 Pkg.
C7	2.2 uF Capacitor, 0603 Pkg.
U1	HMC460LC5
PCB [2]	117808 Evaluation PCB

Reference this number when ordering complete evaluation PCB
 Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

 List of Materia

 Item

 J1 - J2

 J3 - J4

 C4

 C2, C3

 C1

 C5

 C6





GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz